

Dual SCR Power Modules are designed for use in power electronic circuits and equipment under normal operating conditions.

**KEY PARAMETERS**

<b>U<sub>DRM</sub>, U<sub>RRM</sub></b>	<b>up to 1800 V</b>
<b>I<sub>T(AV)</sub></b>	<b>500 A</b>
<b>I<sub>TSM</sub></b>	<b>17000 A</b>
<b>du/dt*</b>	<b>1000 V/μs</b>
<b>di/dt</b>	<b>200 A/μs</b>

\* maximum (non standard) value



**Outline**

See package details for further information

**APPLICATION**

- High Voltage Power Supplies
- Motor Control

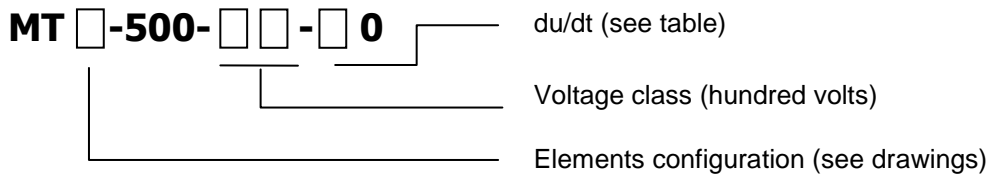
**FEATURES**

- electrically isolated base
- high current capabilities
- high surge current capabilities
- high rates voltages
- low thermal impedance (Aluminium Nitride Insulators)
- tested according to IEC standards
- compact size and small weight

Designed for use in high power industrial and commercial power electronic circuits and equipment where high currents are encountered and high reliability is essential.

**ORDERING INFORMATION**

When ordering please refer to device code builder presented below. Please use the complete part number when ordering, quote or in any future correspondence relating to your order.



**ELECTRICAL PARAMETERS****Voltage ratings**

Voltage class	$U_{RRM}$	$U_{RSM}$	$I_{RRM}$
	V	V	mA
04	400	500	60
06	600	700	
08	800	900	
10	1000	1100	
12	1200	1300	
14	1400	1500	
16	1600	1700	
18	1800	1900	

**du/dt group codes**

Group code	du/dt
	V/ $\mu$ s
0	no specified value
4	200
5	320
6	500
7	1000

### Electrical properties

Parameter		Unit	Test conditions	Value
Average on-state current	$I_{T(AV)}$	A		500
Case temperature	$T_C$	°C		85
RMS on-state current	$I_{T(RMS)}$	A		785
Surge current	$I_{TSM}$	A	$T_j=125^\circ\text{C}$ , $U_R=0,8U_{RRM}$ , $t_p=10\text{ms}$	17000
$I^2t$ – value	$I^2t$	$\text{kA}^2\text{s}$		1445
On-state voltage max.	$U_{TM}$	V	$T_j=25^\circ\text{C}$ , $I_{TM}=1500\text{A}$	1,31
Threshold voltage	$U_{T(T0)}$	V		0,70
Slope resistance	$r_T$	$\text{m}\Omega$		0,44
Latching current	$I_L$	mA	$T_j=25^\circ\text{C}$ , $U_D=12\text{V}$	800
Holding current	$I_H$	mA	$T_j=25^\circ\text{C}$ , $U_D=12\text{V}$	200
Circuit commutated turn-off time (typical)	$t_q$	$\mu\text{s}$	$T_j=125^\circ\text{C}$ , $I_{TM}=250\text{A}$ , $di_R/dt=25\text{A}/\mu\text{s}$ , $du/dt=20\text{V}/\mu\text{s}$ , $U_D=0,67U_{DRM}$ , $U_{RM}=100\text{V}$	150
Turn-On time (typical)	$t_{gt}$	$\mu\text{s}$	$I_{TM}=100\text{A}$ , $U_{DM}=100\text{V}$	10
Rate of rise of on-state current-repetitive	$di/dt$	$\text{A}/\mu\text{s}$	$T_j=125^\circ\text{C}$ , $I_{TM}=3I_{T(AV)}$ , $U_D=0,67U_{DRM}$ , $f=50\text{Hz}$ , $I_{GM}=1\text{A}$ , $di_G/dt=1\text{A}/\mu\text{s}$	200
Critical rate of raise of off-state voltage	$du/dt$	$\text{V}/\mu\text{s}$	$T_j=125^\circ\text{C}$ , $U_D=0,67U_{DRM}$ ,	200 - 1000
Gate current to trigger	$I_{GT}$	mA	$T_j=25^\circ\text{C}$ , $U_D=12\text{V}$	200
Gate voltage to trigger	$U_{GT}$	V	$T_j=25^\circ\text{C}$ , $U_D=12\text{V}$	3
RMS isolation voltage	$U_{isol}$	V	1s, circuit to base, all terminals shorted	2500

### Thermal properties

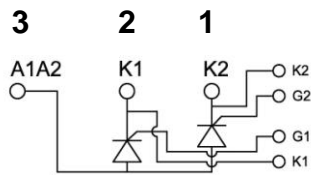
Parameter		Unit	Test conditions	Value
Thermal resistance, junction to case per thyristor/module	$R_{thJC}$	°C/W	DC	0,06/0,03
Thermal resistance, case to heatsink per thyristor/module	$R_{thCh}$	°C/W		0,02/0,01
Operating junction temperature	$T_{jmin} \dots T_{jmax}$	°C		-40...+125
Storage temperature	$T_{stg}$	°C		-40...+125

**Mechanical properties**

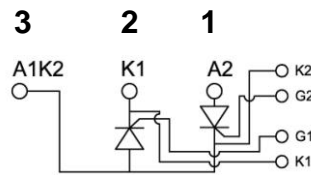
Parameter		Unit	Value
Mounting torque (M6)	M1	Nm	6,00 ±15%
Terminal connection torque (M10)	M2	Nm	12,00 ±10%
Weight	M	g	1490

**Cofigurations**

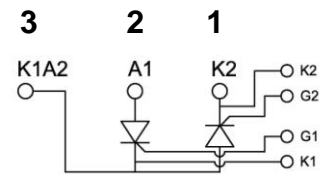
**MTA**  
Terminal number:



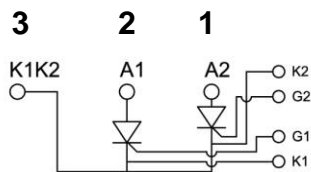
**MTC**  
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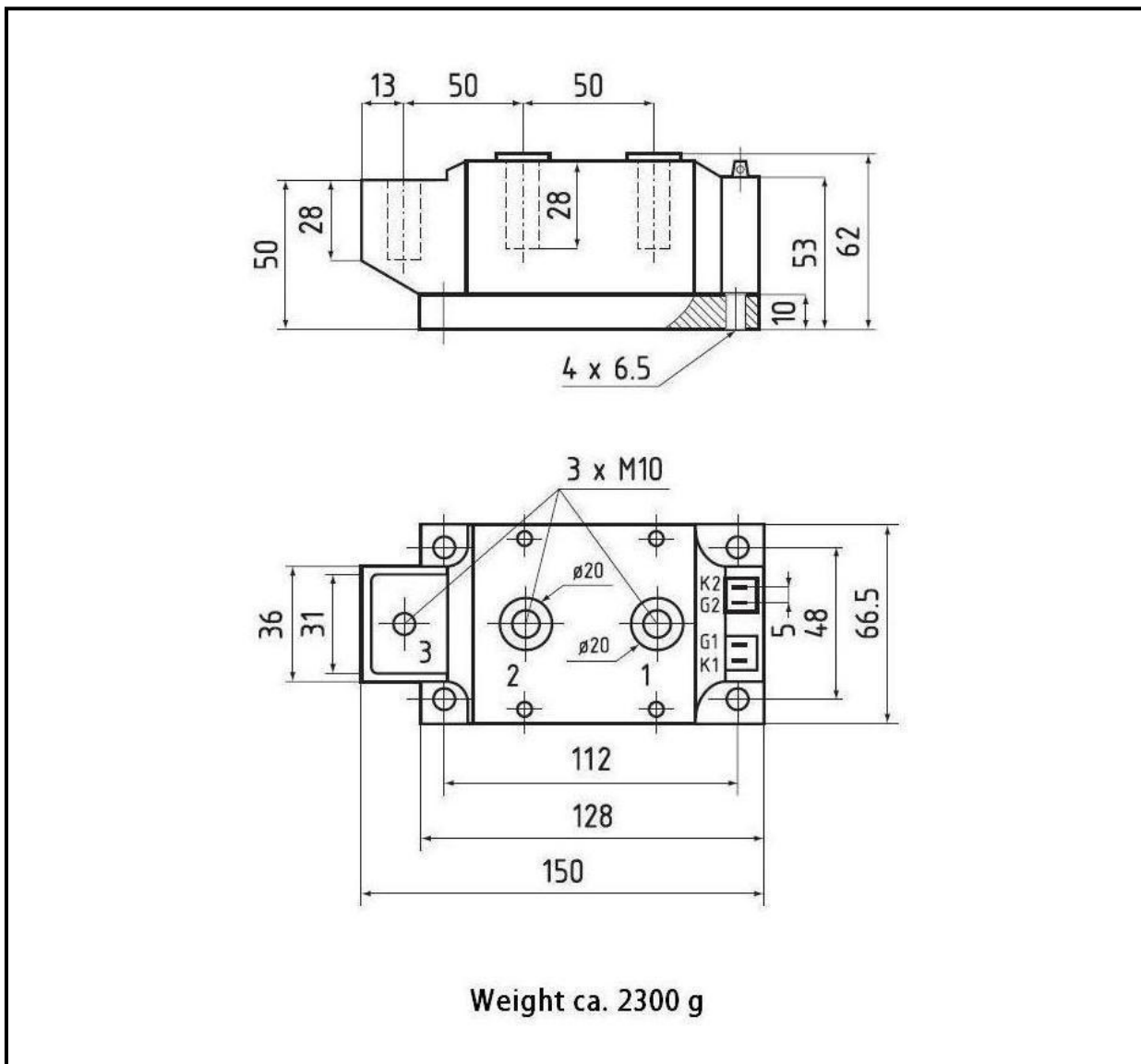


**MTE**  
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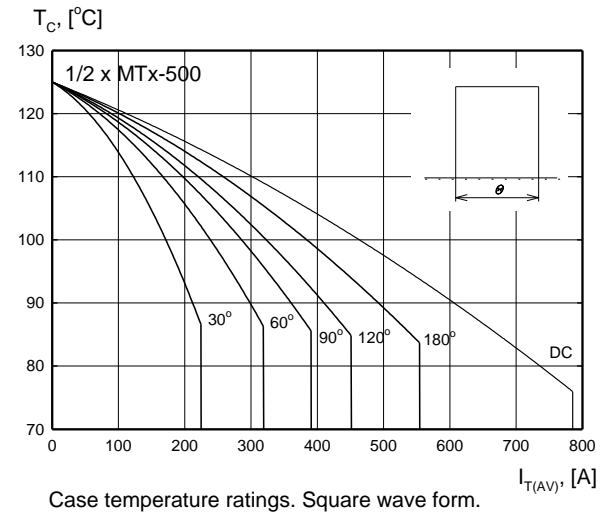
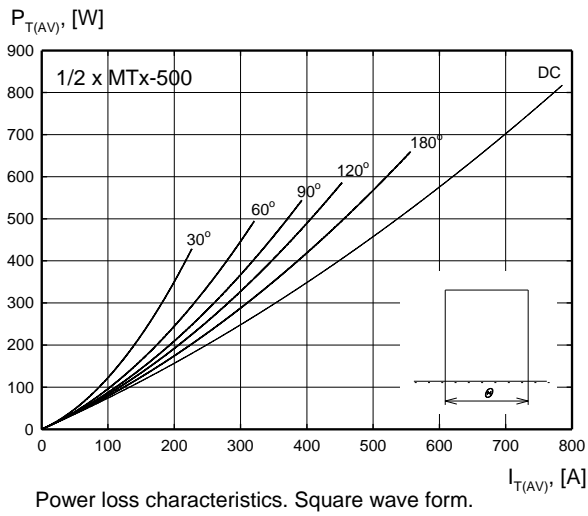
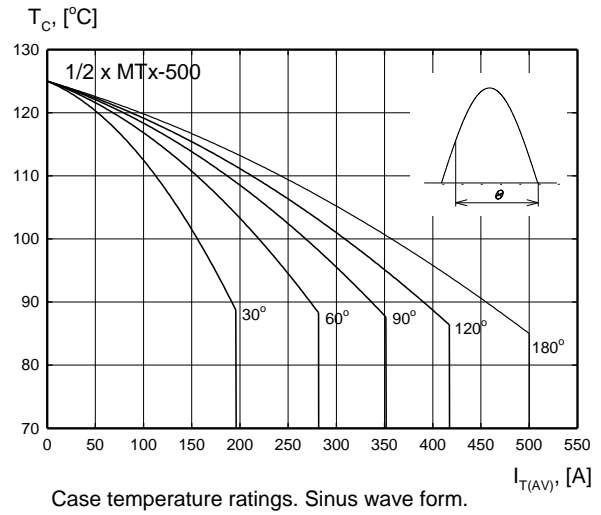
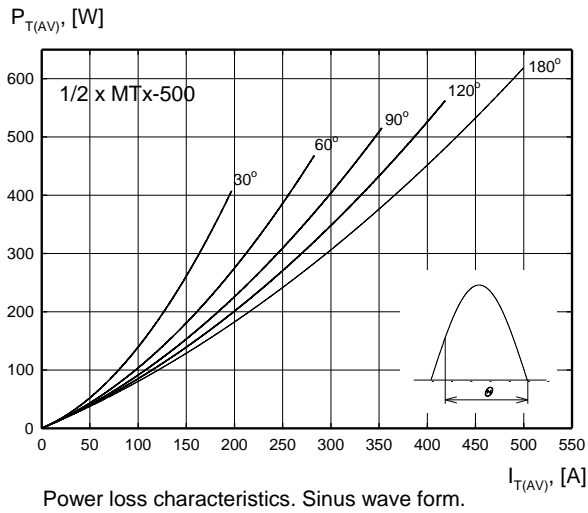
**MTK**  
Terminal number:

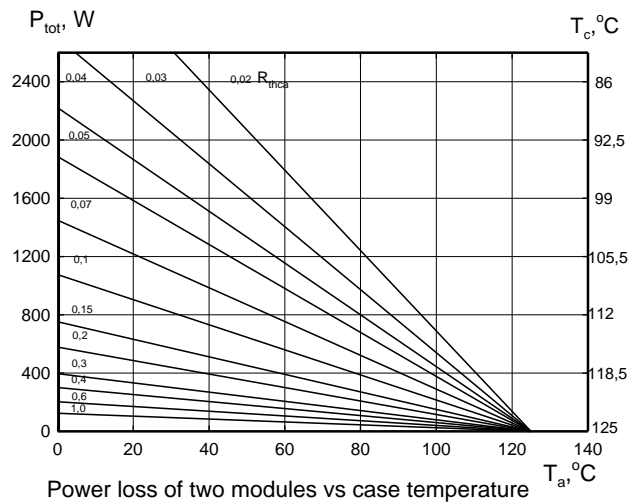
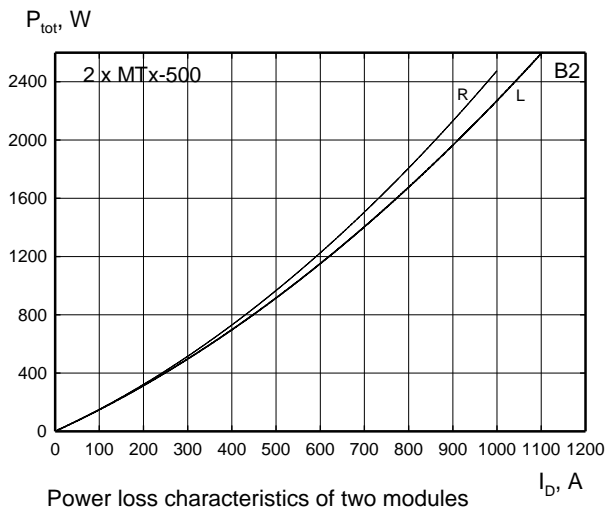
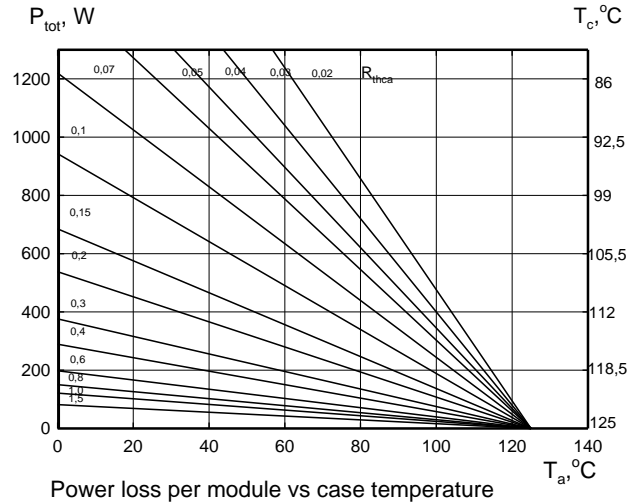
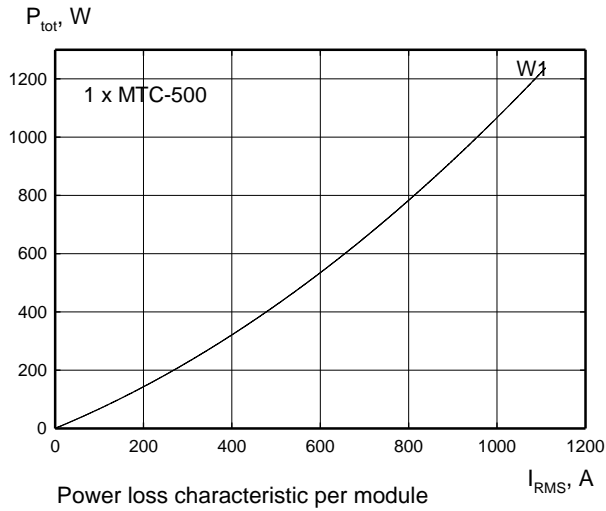


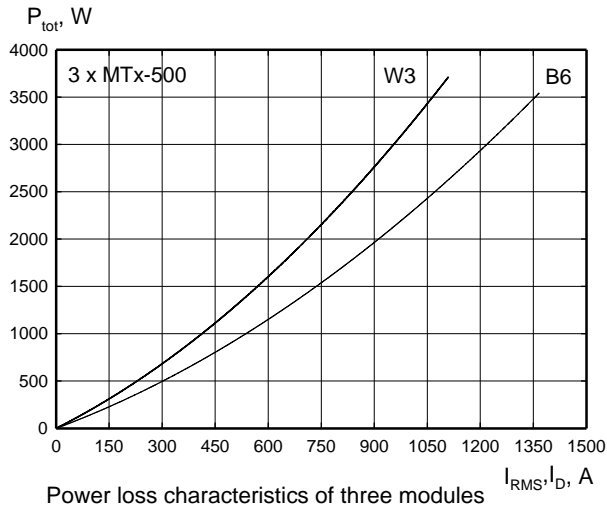
**Package details**

For further package information, please contact Sales & Marketing Department. All dimensions in mm, unless stated otherwise.  
Do not scale.

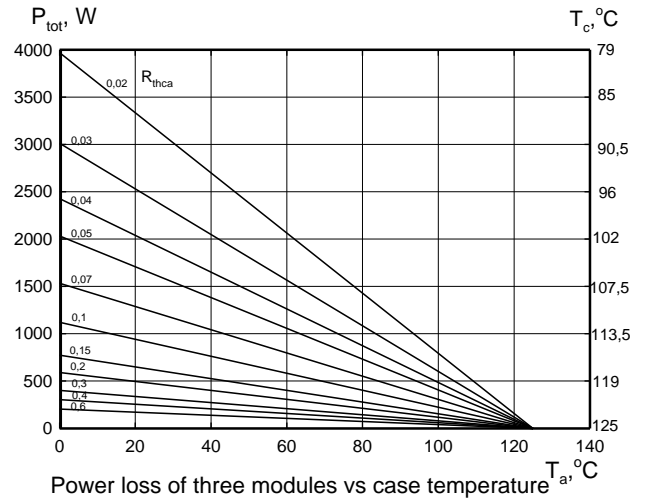
**CHARACTERISTICS**



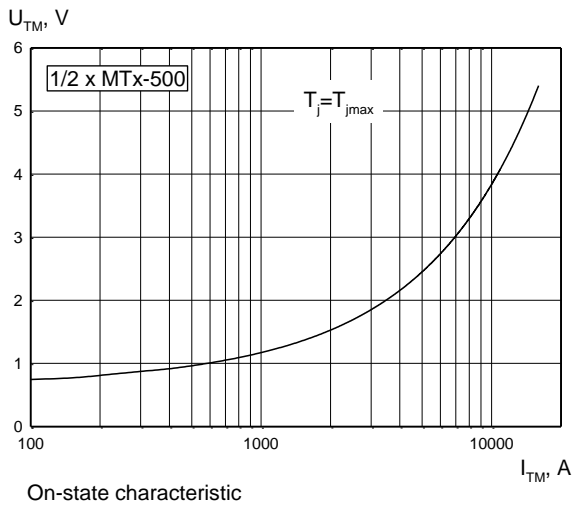




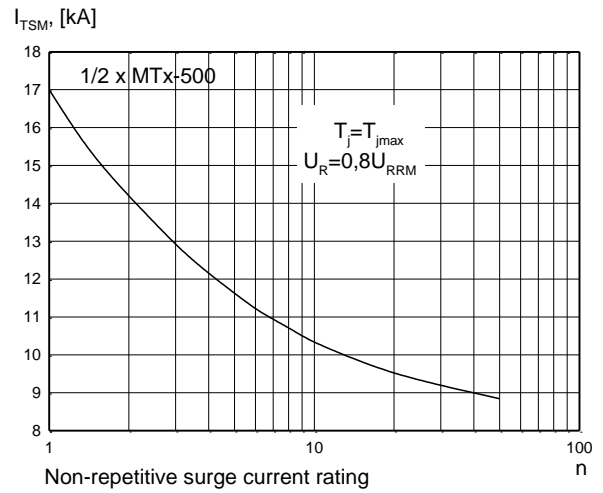
Power loss characteristics of three modules



Power loss of three modules vs case temperature

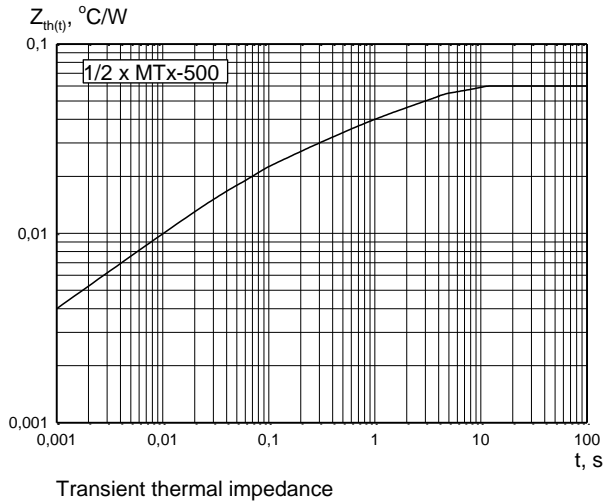


On-state characteristic

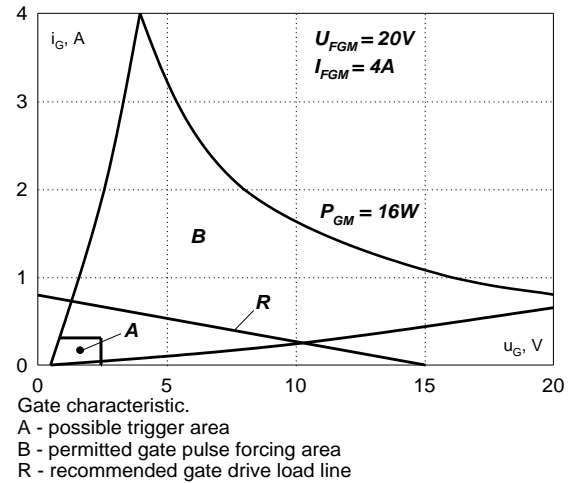
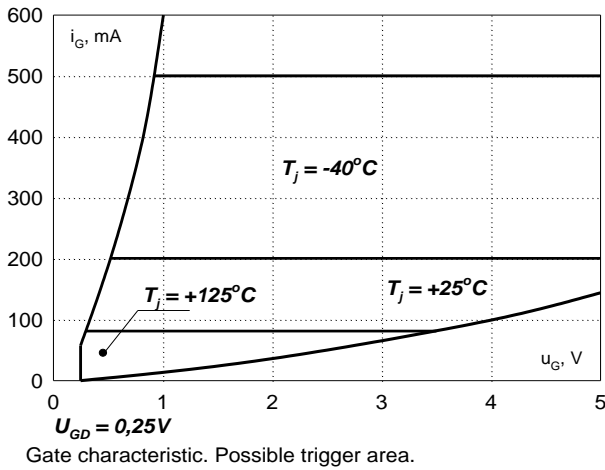


Non-repetitive surge current rating





**GATE CHARACTERISTICS**



**HEATSINKS**

**KUBARA LAMINA SA** has its own proprietary range of extruded aluminium heatsinks designed to optimise the performance of our semiconductors with natural and forced air flow.

**POWER ASSEMBLY CAPABILITY**

**KUBARA LAMINA SA** provides a support for those customers requiring more than a basic semiconductor and offers precisely assembled Power Blocks according to factory or customer standards.